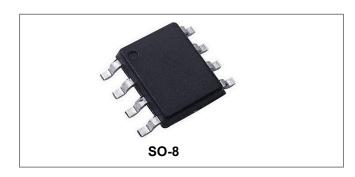






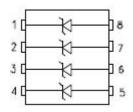
### SMDB03 THRU SMDB24 TVS ARRAY SERIES



### **Description**

The SMDBXX series of TVS array have been designed to provide unidirectional protection for sensitive electronics from damage due to voltage transients caused by electrostatic discharge (ESD), electrical fast transients (EFT), lightning and other voltage-induced transient events. The device can be used to protect combinations of four unidirectional lines.

# **Schematic & Pin Configuration**



#### **Features**

- Protects 3.3, 5, 12, 15, 24 V Components
- Unidirectional
- Provides Electrically Isolated Protection
- 500 W @ 8/20 us
- Protects 4 Lines
- SO-8 Packaging
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Mechanical Characteristics**

- SO-8 Surface Mount Package
- Approximate Weight: 0.1 grams
- PIN #1 Indicator: DOT on top of package
- Packaging: Tubes or Tape & Reel per EIA Standard 481

### **Application**

- RS-232 data lines
- Microprocessor Based Equipment
- Notebooks, Desktops, & Servers
- LAN/WAN Equipment
- Serial and Parallel Port
- Peripherals

# **Absolute Maximum Ratings:**

Parameter	Symbol	Value	Units
Peak Pulse Power, 8/20 µs Wave shape	Р	500	W
Operating Temperature	TJ	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C
Lead Soldering Temperature	T∟	260 (10 Sec.)	°C

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# Electrical Characteristics@25°C

Part Number	Stand-off Voltage Vwm (V) Max	Breakdown Voltage V <sub>BR</sub> @1mA (V) Min	Clamping Voltage Vc @ 1 A (V) Max	Leakage Current I <sub>R</sub> @ Vwm (uA) Max	Capacitance (f = 1MHz) C @ 0V (pF) Max	Temperature Coefficient of V <sub>BR</sub> a(V <sub>BR)</sub> mv/°C Max
SMDB03	3.3	4	7	200	800	-3
SMDB05	5.0	6	9.8	20	600	3
SMDB12	12.0	13.3	19	1	185	10
SMDB15	15.0	16.7	24	1	140	13
SMDB24	24.0	26.7	43	1	90	30

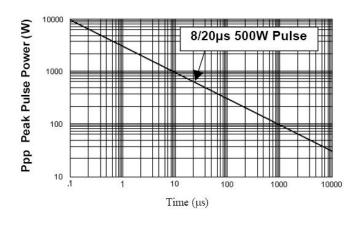
110

100

90

80

# **Ratings and Characteristics Curves**



8 70 60 60 60 50 10 15 20 25 Time (µs)

Figure 1. Peak Pulse Power Vs Pulse Time ( $\mu$ s)

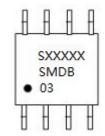
Figure 2. Pulse Wave Form

### **Ordering Information**

Device	Package	Shipping
SMDB03 THRU SMDB24	SO-8 (Pb-Free)	2500pcs / reel
SMDB03TR THRU SMDB24TR	SO-8 (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

 SMDB03
 = Part Number

 S
 = S

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Waveform

Parameters:

tr = 8μs td = 20μs

30

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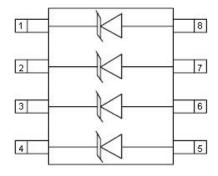




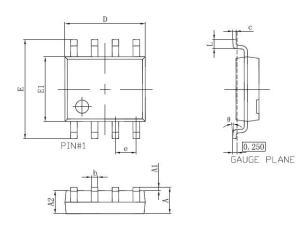
# **Circuit Diagram**

The SMDBxx series of devices are designed to protect up to four data lines. The devices are connected as follows:

✓ The SMDBxx are unidirectional devices and are designed for use on line where the normal operating voltage is above ground. Pins 1, 2, 3, and 4 are connected to the protected lines. Pins 5, 6, 7, and 8 are connected to ground. The ground connections should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.

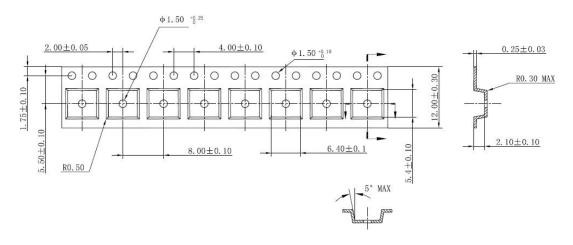


### **Mechanical Dimensions SO-8**



OVMDOL	Millimeters		Inches	
SYMBOL	MIN.	MAX.	MIN.	MAX.
Α	1.350	1.800	0.053	0.071
A1	0.100	0.250	0.004	0.010
A2	1.350	1.750	0.053	0.069
b	0.306	0.510	0.012	0.020
С	0.150	0.300	0.006	0.012
D	4.720	5.120	0.186	0.202
е	1.140	1.400	0.045	0.055
E	5.700	6.300	0.224	0.248
E1	3.750	4.150	0.148	0.163
L	0.300	1.270	0.012	0.050
θ	0°	8°	0°	8°

# **Carrier Tape Specification SO-8**



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